High Power LED Series Chip Scale Package





Use of Samsung's Chip Scale Package technology provide high performance and energy conserving



Features & Benefits

- Utilizes Samsung TF chip technology
- Suitable for use in indoor and outdoor lighting
- Operates at a maximum current of up to 1.4 A
- Compact footprint (2.36 x 2.36 mm)

Applications

- Indoor Lighting: Spotlight, Downlight, MR, PAR
- Outdoor Lighting: Street Light, Tunnel Light, Security Light, Parking Lot Light
- Industrial Lighting: High Bay Light, Low Bay Light
- Consumer Lighting: Torch Light

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1. Characteristics

a) Absolute Maximum Rating

ltem	Symbol	Rating	Unit	Condition
Ambient / Operating Temperature	Ta	-40 ~ +100	٥C	Note 1)
Storage Temperature	T _{stg}	-40 ~ +125	٥C	-
LED Junction Temperature	Tj	135	٥C	-
Forward Current	lF	1400	mA	Note 1)
Peak Pulse Forward Current	I _{FP}	2000	mA	Duty 1/10 pulse width 10ms
Assembly Process Temperature	-	260 <10	°C s	-
ESD (HBM)	-	±2	kV	-

Note:

1) Refer to the derating curve, '3. Typical Characteristics Graph', for proper driving current that maintained below maximum junction temperature.

b) Electro-optical Characteristics

ltem	Unit	Nominal CCT	Cond	ition	Value	
item	Onit	(К)	l⊧ (mA)	Т _ј (°С)	Тур.	
			350	25	168	
			350	85	152	
Luminous Flux (Φ_v)	Im	3500 (80 CRI)	700	85	283	
			1000	85	381	
			1400	85	492	
			350	25	2.92	
			350	85	2.82	
Forward Voltage (V $_{\rm F})$	V		700	85	2.97	
			1000	85	3.08	
			1400	85	3.20	
Thermal Resistance (junction to solder point)	K/W				2	
Beam Angle	0				120	

Note:

Samsung maintains measurement tolerance of: luminous flux = $\pm 7\%$, forward voltage = ± 0.1 V



c) Luminous Flux Characteristics (T_s = 85 °C)

	Sorting @ 350 mA (Im)		Calculated Mini	imum Flux² ⁾ (lm)	
Flux Rank	Flux Range ¹⁾	Sub Rank	@ 350 mA	@ 700 mA	@ 1050 mA	@ 1500 mA
E3	80 ~ 110	E1, F1, G1	80	149	200	259
F3	90 ~ 120	F1, G1, H1	90	167	226	291
G3	100 ~ 130	G1, H1, J1	100	186	251	324
НЗ	110 ~ 140	H1, J1, K1	110	205	276	356
J3	120 ~ 150	J1, K1, M1	120	223	301	388
K3	130 ~ 160	K1, M1, N1	130	242	326	421
МЗ	140 ~ 170	M1, N1, P1	140	260	351	453
N3	150 ~ 180	N1, P1, Q1	150	279	376	485
P3	160 ~ 190	P1, Q1, R1	160	298	401	518
Q3	170 ~ 200	Q1, R1, S1	170	316	426	550
R3	180 ~ 210	R1, S1, T1	180	335	451	582
S3	190 ~ 220	S1, T1, U1	190	353	476	615
Т3	200 ~ 230	T1, U1, V1	200	372	501	647
U3	210 ~ 240	U1, V1, W1	210	391	526	679
V3	220 ~ 250	V1, W1, X1	220	409	551	712
W3	230 ~ 260	W1, X1, Y1	230	428	576	744
X3	240 ~ 270	X1, Y1, Z1	240	446	601	776
Y3	250 ~ 280	Y1, Z1, 11	250	465	627	809
Z3	260 ~ 290	Z1, 11, 21	260	484	652	841

Notes:

1) Samsung maintains measurement tolerance of: luminous flux = ± 7 %, CRI = ± 3

2) Calculated minimum flux values are for reference only

2. Product Code Information

<u>1</u>	<u>2</u>	<u>3</u>	4	5	<u>6</u>	<u>7</u>	<u>8</u>	<u>9</u>	<u>10</u>	<u>11</u>	<u>12</u>	13	14	15	16	17	18	8
S	С	Р	8	U	т	F	1	н	E	L	1	U	к	M	3	4	E	:
Dig	jit		PKG Info	ormation		Code					Sp	ecificati	on					
1 2	3	Sams	ung Chip	Scale Pa	ackage	SCP												
						7	CRI 70											
4			С	RI		8	CRI 80											
						9	CRI 90											
					W	2700K												
						v	3000K											
						U	3500K											
5		CCT(K)			т	4000K												
						R	5000K											
						Q	5700K											
						Р	6500K											
6			Chip	Shape		т	Square	type										
78	9		Pro	duct		F1H	Chip ver	rsion										
10 11	12		Product	Purpose		EL1	FEC for	lighting										
						W	2700K											
						v	3000K											
						U	3500K											
13			CCT (K)		т	4000K												
						R	5000K											
						Q	5700K											
						Р	6500K											
				_		к	Full E	Bin for Ma	cAdam 5	-Step								
14			MacAda	am Step		U	Full E	Bin for Ma	cAdam 3	-Step								
						F 3	90- 120		F1	90-100								
						G 3	100- 130		G1	100-110	F3							
						H 3	110- 140		H1	110- 120		G3						
						J 3	120- 150		J1	120- 130			H3		_			
						К 3	130~160		K1	130~140				13				
						M 3	140~170			140~150				K3				
15 1	16		Lumino	ous Flux		N 3	150~180			150~160					М 3			
						P 3	160~190			160~170						N 3		
						Q 3	170~200		Q1	170~180							P 3	Q 3
						Digit 16		nber of hig	gher bin(s 3 = 130~1		n. spec.							
17 1	18	F	orward V	/oltage (V	f)	4 E	2.7 ~	3.1 V										

a) Luminous Flux Bins (IF = 350 mA, Ts = 85 °C)

CRI/		Flux rank											
Nomin	al CCT (K)	Eı	F1	Gı	Hı	Jı	Kı	Мı	Nı	Pı	Qı	Rı	Sı
	(min. flux)	80	90	100	110	120	130	140	150	160	170	180	190
	2700							SCP7WTF1HEL1W		/ <i>◇</i> M34E			
70	3000								SCP7V	VTF1HEL1V <i>∕</i> N34E			
	3500				•				SCP7U	ITF1HEL1U	<i>⇔</i> N34E		
	4000									SCP71	TF1HEL1T	∕ ∕₽34 Е	
	5000		÷	•	-		-			SCP7R	TF1HEL1R	∕ ∕₽34 E	
	5700									SCP7Q	TF1HEL1G	¢ ∕P34E	
	6500								SCP7P	PTF1HEL1P�N34E			
	2700						SCP8W	/TF1HEL1W <i></i> ∕K34E					
	3000						SCP8V	/TF1HEL1V�K34E					
	3500							SCP8U	SCP8UTF1HEL1U \Diamond M34E				
80	4000							SCP87	TF1HEL1T	<i>⊘</i> M34E			
	5000			-	-				SCP8R	TF1HEL1R	<i>⊘</i> N34E		
	5700								SCP8Q	TF1HEL1Q	∕∕ N34E		
	6500							SCP8F	PTF1HEL1P	<i>◇</i> M34E			
	2700			SCP9W	TF1HEL1W	/◇G34E							
	3000			SCP9V	TF1HEL1V	∕ ∕G34E							
90	3500				SCP9UTF1HEL1U		<i>⇔</i> H34E						
	4000				SCP91	TF1HEL1T	<i>⇔</i> H34E						
	5000				SCP9R	TF1HEL1R	<i>⇔</i> H34E						

Notes:

1) $\,\, \diamondsuit$: MacAdam step code, K(MacAdam 5-step) / U(MacAdam 3-step)

b) Color Bins (I_F = 350 mA, T_s = 85 °C)

Nominal CCT (K)	CRI (R₃)	Color Rank	Chromaticity Bins
2700, 3000, 3500, 4000, 5000, 5700, 6500	70		
2700, 3000, 3500, 4000, 5000, 5700, 6500	80	K (Full Bin for MacAdam 5-step) U (Full Bin for MacAdam 3-step)	☆K ☆U
2700, 3000, 3500,4000,5000	90		

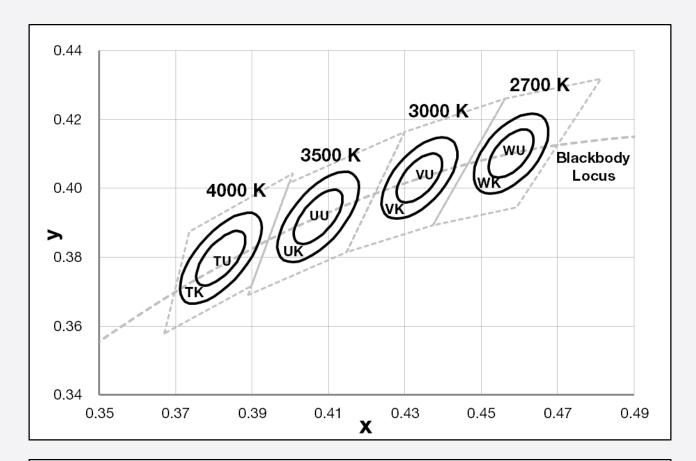
Notes:

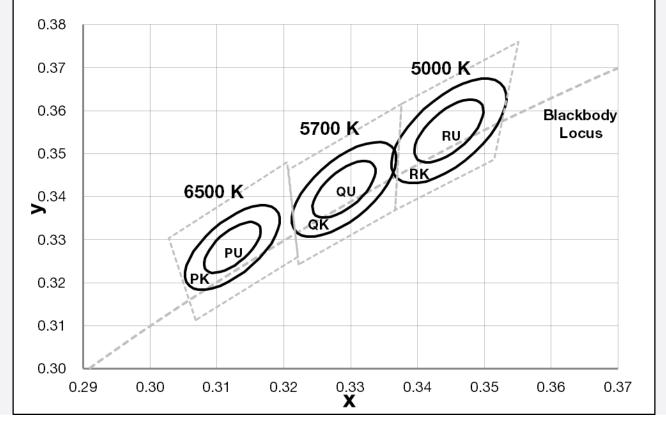
1) 🕆 : Nominal CCT code, W(2700K)/V(3000K)/U(3500K)/T(4000K)/R(5000K)/Q(5700K)/P(6500K)

c) Voltage Bins ($I_F = 350 \text{ mA}, T_s = 85 \text{ °C}$)

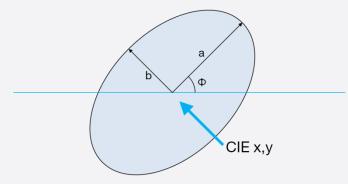
CRI (Ra)	Nominal CCT (K)	Product Code	Voltage Rank	Voltage Bin	Voltage Range (V)
			4E	4E	2.7 ~ 3.1







e) Chromaticity Region & Coordinates (I_F = 350 mA, $T_{\rm s}$ = 85 °C)



	ССТ	Cent	er point	Major-axis	Minor-axis	Rotation
	(К)	CIE x	CIE y	а	b	Φ
	2700	0.4578	0.4101	0.0081	0.0042	53.70
	3000	0.4338	0.4030	0.0083	0.0041	53.22
	3500	0.4073	0.3917	0.0093	0.0041	54.00
3 step	4000	0.3818	0.3797	0.0094	0.0040	53.72
	5000	0.3447	0.3553	0.0082	0.0035	59.62
	5700	0.3287	0.3417	0.0075	0.0032	59.10
	6500	0.3123	0.3282	0.0067	0.0029	58.57
	2700	0.4578	0.4101	0.0135	0.0070	53.70
	3000	0.4338	0.4030	0.0138	0.0068	53.22
	3500	0.4073	0.3917	0.0155	0.0068	54.00
5 step	4000	0.3818	0.3797	0.0157	0.0067	53.72
	5000	0.3447	0.3553	0.0137	0.0058	59.62
	5700	0.3287	0.3417	0.0125	0.0053	59.10
	6500	0.3123	0.3282	0.0112	0.0048	58.57

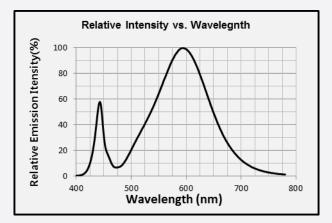
Note:

Samsung maintains measurement tolerance of: $Cx, Cy = \pm 0.005$

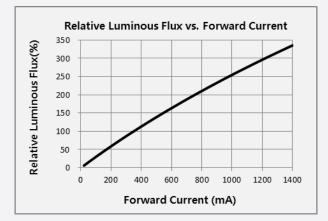
3. Typical Characteristics Graphs

3000K/CRI70

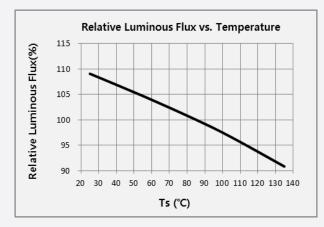
a) Spectrum Distribution ($I_F = 350 \text{ mA}, T_s = 85 \text{ °C}$)



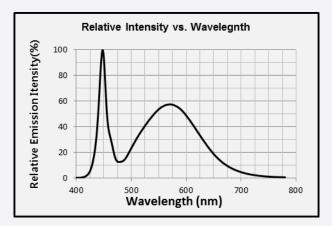
b) Forward Current Characteristics (T_s = 85 °C)

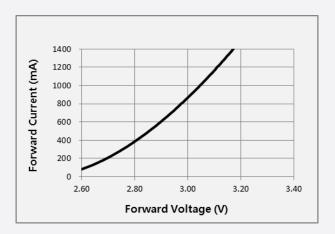


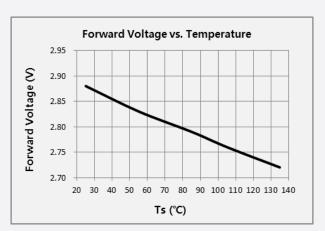
c) Temperature Characteristics (I_F = 350 mA)





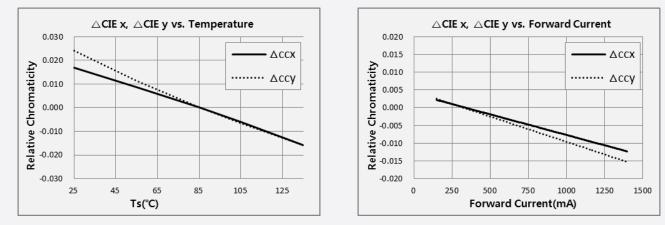




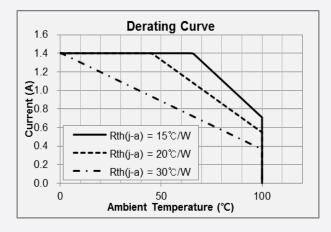


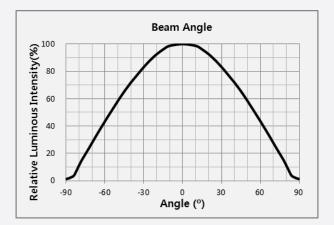
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d) Color Shift Characteristics (I_F = 350 mA, T_s = 85 °C)

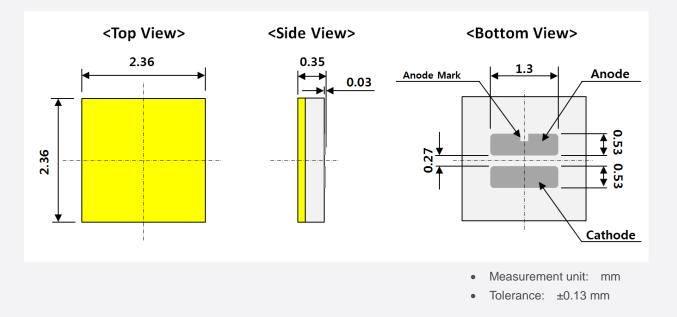








4. Outline Drawing & Dimension



Precautions:

- 1) Pressure on the LEDs will influence to the reliability of the LEDs. Precautions should be taken to avoid strong pressure on the LEDs. Do not put stress on the LEDs during heating.
- 2) Re-soldering should not be done after the LEDs have been soldered. If re-soldering is unavoidable, LED's characteristics should be carefully checked before and after such repair.
- Do not stack assembled PCBs together. Since materials of LEDs is soft, abrasion between two PCB assembled with LED might cause catastrophic failure of the LEDs.

5. Reliability Test Items & Conditions

a) Test Items

Test Item	Test Condition	Test Hour / Cycle
Room Temperature Life Test	25 °C, Derated maximum current	1000 h
High Temperature Life Test	85 °C, Derating maximum current	1000 h
High Temperature Humidity Life Test	60 °C, 90% RH, Derating maximum current	1000 h
Low Temperature Life Test	-40 °C, Derating maximum current	1000 h
Temperature Humidity Cycle Test	-10 ℃↔25 ℃/Dry, 25 ℃ ↔ 65 ℃ 95% R.H. Derating maximum current	10 cycles
Powered Temperature Cycle Test	-40 °C / 85 °C each 20 min, 100 min transfer power on/off each 5 min, Derating maximum current	100 cycles
Thermal Shock	-45 °C / 15 min \leftrightarrow 125 °C / 15 min temperature change within 5 min	500 cycles
High Temperature Storage	120 °C	1000 h
Low Temperature Storage	-40 °C	1000 h
ESD (HBM)	R ₁ : 10 MΩ R ₂ : 1.5 kΩ C: 100 pF V: ±2 kV	5 times
ESD (MM)	R ₁ : 10 MΩ R ₂ : 0 C: 200 pF V: ±0.2 kV	5 times
Vibration Test	20~2000-20 Hz, 200 m/s ² , sweep 4 min X, Y, Z 3 direction, each 1 cycle	4 cycles
Mechanical Shock Test	1500 g, 0.5 ms 3 shocks each X-Y-Z axis	5 cycles

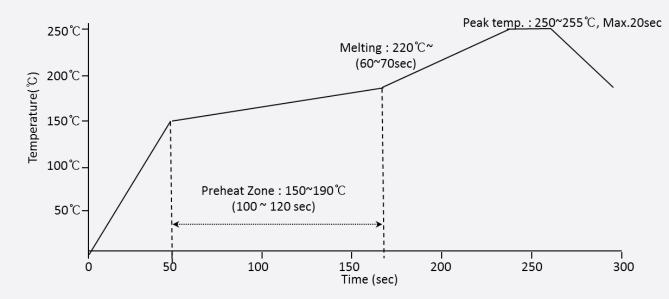
b) Criteria for Judging the Damage

ltem	Symbol	Test Condition	Lir	nit
nem	Symbol	(T _s = 25 ^o C)	Min.	Max.
Forward Voltage	V _F	I _F = 350 mA	Init. Value * 0.9	Init. Value * 1.1
Luminous Flux	Φ _v	I _F = 350 mA	Init. Value * 0.7	Init. Value * 1.1

6. Soldering Conditions

a) Reflow Conditions (Pb free)

Reflow frequency: 2 times max.



b) Manual Soldering Conditions

No more than 5 seconds @ max. 300 $^{\rm o}{\rm C},$ under soldering iron.

7. Tape & Reel

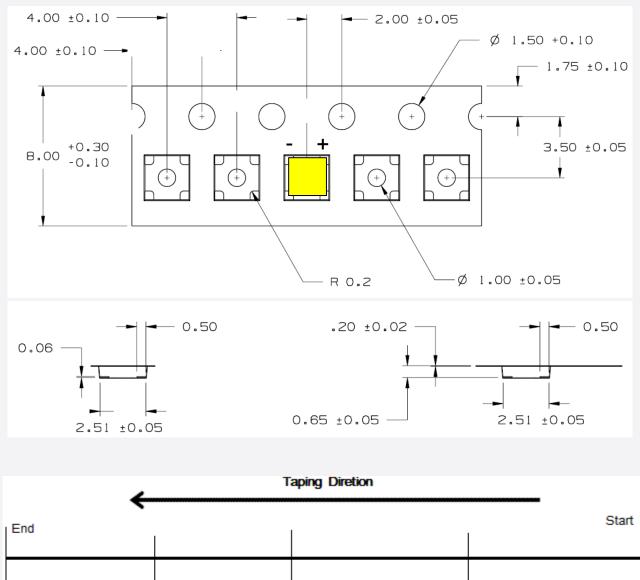
a) Taping Dimension

More than 40 mm

Unloaded tape

Mounted with

LED package



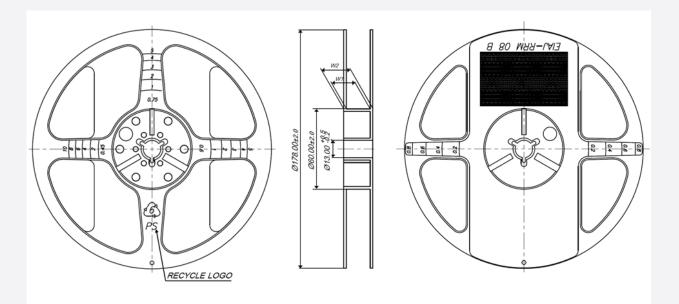
More than 100~200 mm

Unloaded tape

Leading part more than

200~400 mm

(unit: mm)



Width	W1	W2
8mm	9±0.3	11.9±1.0

Notes:

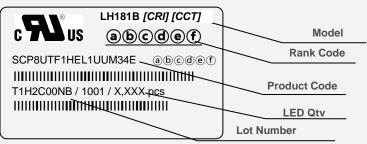
- 1) Quantity: 2,000 Qty/reel
- 2) Cumulative tolerance: Cumulative tolerance / 10 pitches is ±0.2 mm
- Adhesion strength of cover tape: Adhesion strength is 0.1-0.7 N when the cover tape is turned off from the carrier tape at 10° angle to the carrier tape
- 4) Packaging: P/N, Manufacturing data code no. and quantity are indicated on the aluminum packing bag

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8. Label Structure

a) Label Structure



Note: Denoted Bin ID and product code above is only an example

Rank Code:

- (a)(b): Chromaticity bin (refer to page 6)
- ©d: Luminous Flux bin (refer to page 6,7)
- (e)(f): Voltage bin (refer to page 6,9)

b) Lot Number

(2)

The lot number is composed of the following characters:

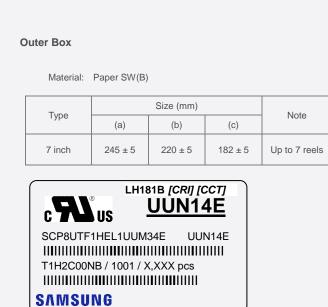


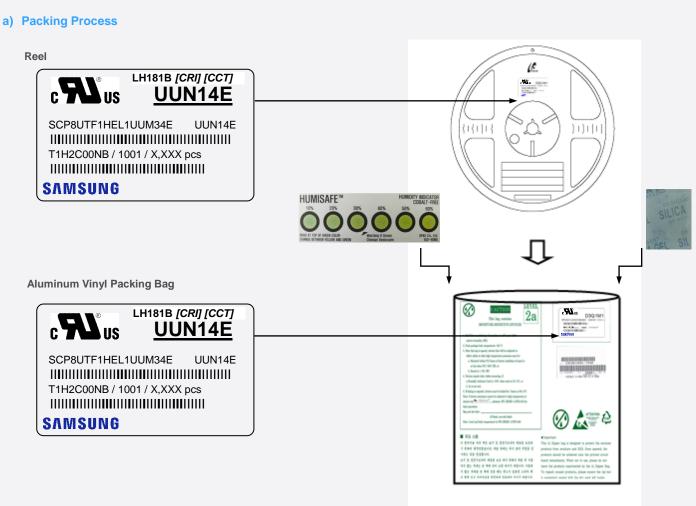
- ① : T (T: Taping ID)
 - : 1 (1: LED Manufacture Line)
- (3) : Year (G:2016, H: 2017, ...)
- (4) : Month (1, 2, ..., 7: July, ..., A: Oct., B: Nov., C: Dec.)
- (5) : Day (1~9, A: 10, ..., K: 20, ..., U: 30, V:31)
- 6789 : Product serial number (0001 ~ 9999)

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b) Aluminum Vinyl Packing Bag



c) Silica Gel & Humidity Indicator Card inside Aluminum Vinyl Bag



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10. Precautions in Handling & Use

- For over-current protection, users are recommended to apply resistors connected in series with the LEDs to mitigate sudden change of the forward current caused by shift of forward voltage.
- 2) This device should not be used in any type of fluid such as water, oil, organic solvent, etc. When cleaning is required, IPA is recommended as the cleaning agent. Some solvent-based cleaning agent may damage the silicone resins used in the device.
- 3) When the device is in operation, the forward current should be carefully determined considering the maximum ambient temperature and corresponding junction temperature.
- 4) LEDs must be stored in a clean environment. If the LEDs are to be stored for three months or more after being shipped from Samsung, they should be packed with a nitrogen-filled container (shelf life of sealed bags is 12 months at temperature 0~40 °C, 0~90 % RH).
- After storage bag is opened, device subjected to soldering, solder reflow, or other high temperature processes must be:
 a. Mounted within 672 hours (28 days) at an assembly line with a condition of no more than 30 °C / 60 % RH, or
 b. Stored at <10 % RH
- 6) Repack unused devices with anti-moisture packing, fold to close any opening and then store in a dry place.
- 7) Devices require baking before mounting, if humidity card reading is >60 % at 23 ± 5 °C.
- 8) Devices must be baked for 1 hour at 60 ± 5 °C, if baking is required.
- 9) The LEDs are sensitive to the static electricity and surge current. It is recommended to use a wrist band or antielectrostatic glove when handling the LEDs. If voltage exceeding the absolute maximum rating is applied to LEDs, it may cause damage or even destruction to LED devices. Damaged LEDs may show some unusual characteristics such as increase in leakage current, lowered turn-on voltage, or abnormal lighting of LEDs at low current.
- 10) VOCs (Volatile Organic Compounds) can be generated from adhesives, flux, hardener or organic additives used in luminaires (fixtures). Transparent LED silicone encapsulant is permeable to those chemicals and they may lead to a discoloration of encapsulant when they exposed to heat or light. This phenomenon can cause a significant loss of light emitted (output) from the luminaires. In order to prevent these problems, we recommend users to know the physical properties of materials used in luminaires and they must be carefully selected.

Legal and additional information.

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